

**5V, 3.5A, High Efficiency COT Mode Synchronous Buck Converter**

**General Description**

The EM5841D is a high efficiency synchronous buck converter. It can support 3.5A continuous output current. The constant on-time control provides fast transient response and allows a small footprint when designed all ceramic output capacitors. Other features include internal soft-start, under-voltage protection, over-voltage protection, cycle-by-cycle current limit and thermal shutdown function. With aforementioned functions, these parts provide customers a compact, high efficiency, well-protected and cost-effective solutions. These parts are available in DFN3.0X3.0-10 package.

**Ordering Information**

Part Number	Package	Remark
EM5841DVT	DFN3.0X3.0-10	FCCM

**Features**

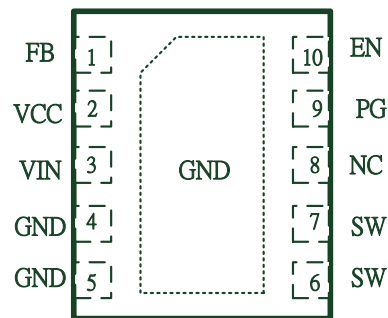
- Constant On Time Control
- 2.7V to 5.5V Operating Input Range
- 0.6V, 1% Voltage Reference Accuracy
- Up to 3.5A Output Current
- Stable with Low ESR Output Ceramic Capacitors
- Default 1 MHz frequency operation
- Internal Soft Start / Soft Stop
- 80m and 60m Internal Power MOSFET Switches
- Cycle-by-Cycle Current Limit
- Output Under Voltage Protection
- Output Over Voltage Protection
- Power Good Indicator for Power Sequence Control
- Quickly Output Wake- up Response
- FCCM Mode
- Available in a DFN3.0X3.0-10 Package

**Applications**

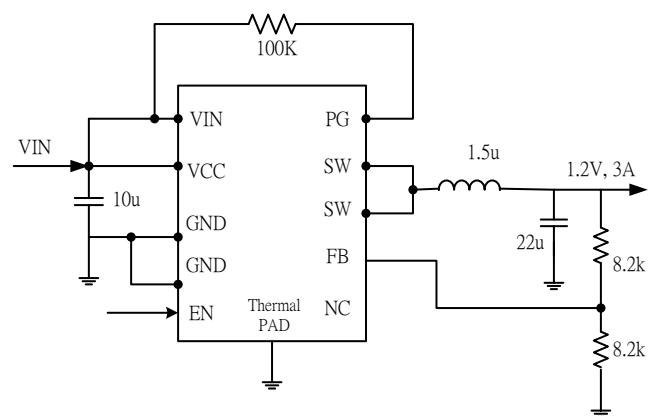
- Notebook & Tablet
- Graphic Cards & MB
- Low Voltage Logic Supplies
- Chipset Supplies
- Server System
- SMPS Post Regulators



**Pin Configuration**



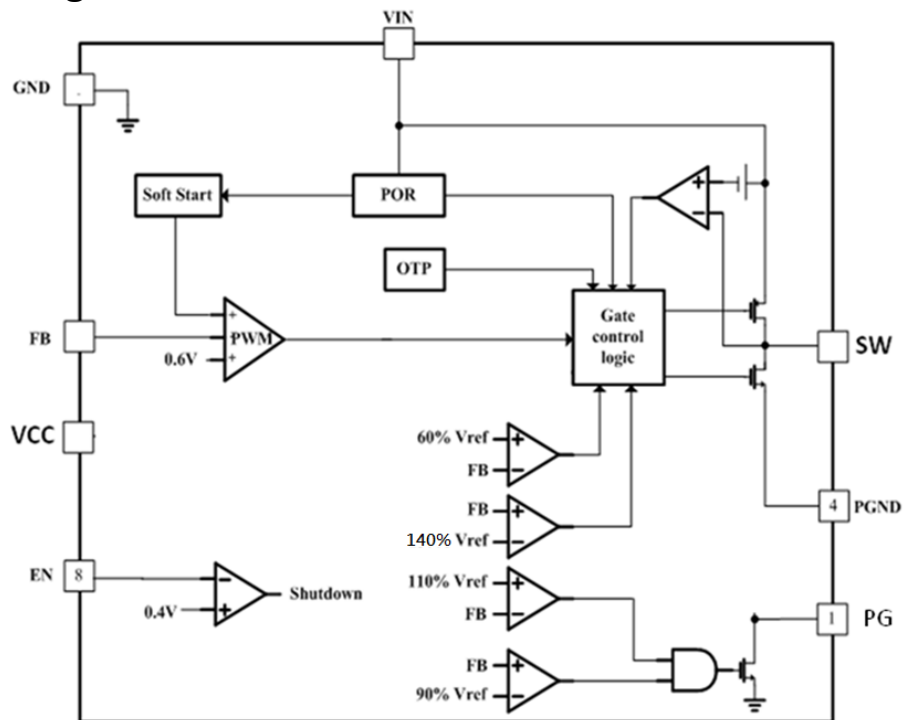
**Typical Application Circuit**



## Pin Assignment

Pin Name	Pin No.	Pin Function
FB	1	<b>Feedback Voltage.</b> A resistor divider from the output to GND is used to set the regulation voltage.
VCC	2	<b>Supply Voltage.</b> This pin provides the bias supply for the EM5841. Ensure that a decoupling capacitor is placed near the IC.
VIN	3	<b>Main Power Conversion Input &amp; Gate driver voltage supply.</b>
PGND	4	<b>Power Ground.</b>
PGND	5	<b>Power Ground.</b>
SW	6,7	<b>Switching node output.</b> Connect to external inductor.
NC	8	<b>Not Connect.</b>
PG	9	<b>Power Good Indicator.</b> Requires external pull-up resistor.
EN	10	<b>Enable.</b> Pulling this pin lower than 0.4V disables the converter.

## Function Block Diagram



### Absolute Maximum Ratings (Note1)

- $V_{IN}$  ----- -0.3V to +6.0V
- $V_{CC}$  ----- -0.3V to +6.0V
- $V_{SW}$  ----- -0.3V to +6.0V
- <20ns----- -5.0V to +9.0V
- EN,VFB,PG----- -0.3V to +6.0V
- Package Thermal Resistance,  $\theta_{JA}$ , -----70°C/W
- Power Dissipation, PD @  $T_A = 25^\circ\text{C}$ , ----- 1.45W
- Junction Temperature-----150°C
- Lead Temperature (Soldering, 10 sec.)----- 260°C
- Storage Temperature ----- -65°C to 150°C
- ESD susceptibility (Note3)
  - HBM (Human Body Mode)----- 2KV
  - MM (Machine Mode)----- 200V

### Recommended Operating Conditions (Note4)

- Control Voltage,  $V_{CC}, V_{IN}$  ----- +2.7V to +5.5V
- Junction Temperature ----- -40°C to 125°C
- Ambient Temperature ----- -40°C to 85°C

### Electrical Characteristics

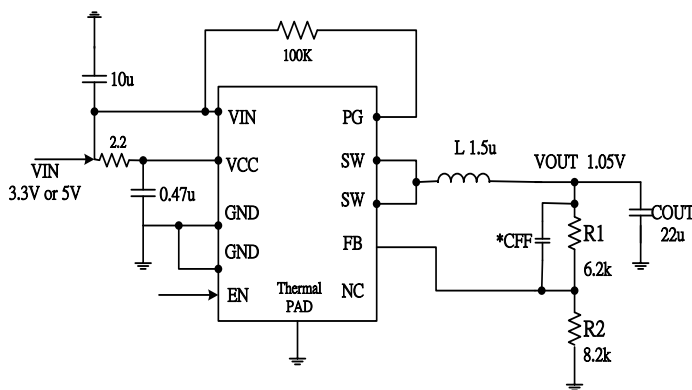
$V_{IN}=5V, T_A=25^\circ\text{C}$ , unless otherwise specified

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
<b>Supply Input Section</b>						
Vcc Shutdown Current	$I_{SD}$	$V_{EN}=0V$		0.1		$\mu\text{A}$
Supply Voltage	$V_{in}$		2.7		5.5	V
Power Voltage	$V_{CC}$		2.7		5.5	V
VCC Quiescent Current	$I_{CQ}$			300		$\mu\text{A}$
Power on Reset Threshold	UVLO	$V_{IN}\&V_{CC}$ wake up	2.2	2.4	2.6	V
Power on Reset Hysteresis	UVLO			0.3		V
<b>Enable</b>						
Enable High Voltage	$V_{EN\_H}$		1.2			V
Enable Low Voltage	$V_{EN\_L}$				0.4	V
Enable Input Current		$V_{EN}=2V$		2		$\mu\text{A}$
		$V_{EN}=0V$		0		$\mu\text{A}$
<b><math>T_{ON} / T_{OFF}</math></b>						
Frequency	$F_S$	$V_{IN}=5V, V_{OUT}=1.2V, I_{OUT}=1A$		1		MHz
Min. Off Time	$T_{OFF}$		50	100	150	ns
Maximum Duty Cycle	$D_{MAX}$	$V_{IN}=V_{CC}\geq 4.5V$	75			%
		$V_{IN}=V_{CC}\geq 3V$	70			%
<b>Switch</b>						
High Side MOS ON Resistance	$R_{ON\_HS}$	$V_{CC}=3.6V$		80		m $\Omega$
High Side MOS Current Limit	$I_{CL}$		5	6		A
Low Side MOS ON Resistance	$R_{ON\_LS}$	$V_{CC}=3.6V$		60		m $\Omega$

Reference Voltage						
Internal Reference	$V_{REF}$		0.594	0.6	0.606	V
PG Indicator						
PG Upper Trip Threshold	$V_{POKU}$			130		%
PG Lower Trip Threshold	$V_{POKL}$			90		%
PG Delay	$T_{D\_POK}$			60		us
PG Leakage Current	$I_{L\_POK}$				1	uA
Protection section						
FB Under Voltage Protection	$V_{FB\_UVP}$	FB falling		50	60	70 %
UVP delay time	$T_{D\_UVP}$				7.5	10 us
FB Over Voltage Protection	$V_{FB\_OVP}$	FB rising		130	140	150 %
OVP delay time	$T_{D\_OVP}$				7.5	10 us
Soft-Start Interval	$T_{SS}$	EN to PG active				400 us
VOUT Discharge Resistance					100	$\Omega$
Thermal Shutdown	$T_{SD}$				150	$^{\circ}C$
Thermal Shutdown Hysteresis	$T_{SD\_HYS}$				30	$^{\circ}C$

- Note 1.** Stresses listed as the above “Absolute Maximum Ratings” may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may remain possibility to affect device reliability.
- Note 2.**  $\theta_{JA}$  is measured in the natural convection at  $T_A=25^{\circ}C$  on a 4-layers high effective thermal conductivity test board with minimum copper area of JEDEC 51-7 thermal measurement standard.
- Note 3.** Devices are ESD sensitive. Handling precaution is recommended.
- Note 4.** The device is not guaranteed to function outside its operating conditions.

### Reference Values of Feedback Networks and output LC filter combination



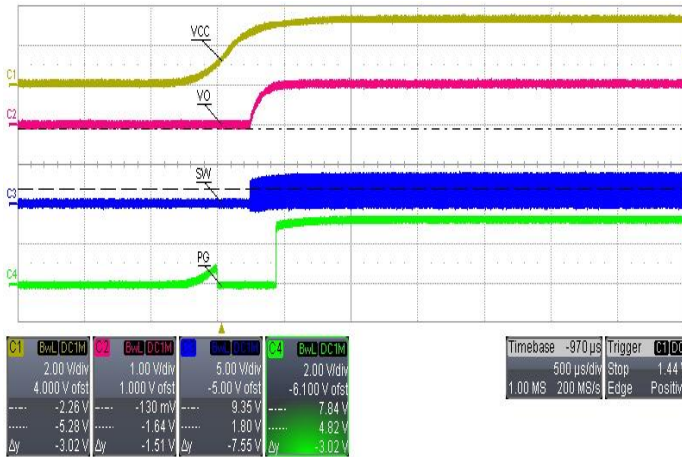
VOUT(V)	R1(k $\Omega$ )	R2(k $\Omega$ )	L (uH)	COU (uF)	*CFF(pF)
3.3	37	8.2	2.2	22~66	22p~470p
1.8	16.5	8.2	1.5	22~66	
1.2	8.2	8.2	1.5	22~66	
1.05	6.2	8.2	1.5	22~66	
1	5.6	8.2	1.5	22~66	

\* CFF is chosen for improving the transient load response

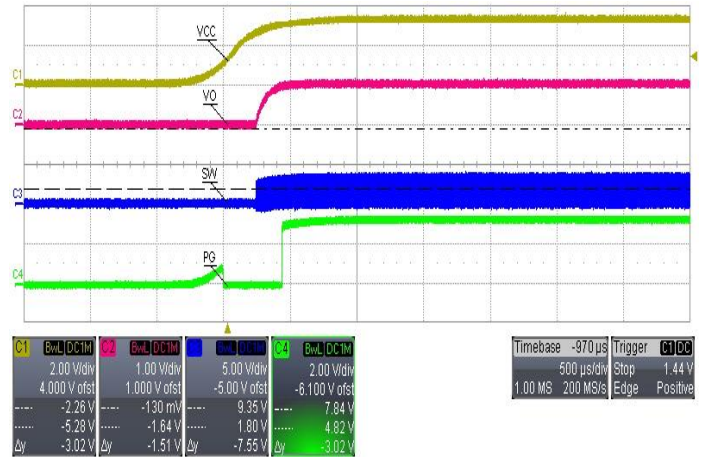
**Typical Operating Characteristics**

Ta=25°C, C<sub>IN</sub>=10uF, C<sub>OUT</sub>=22uF, L=1.5uH

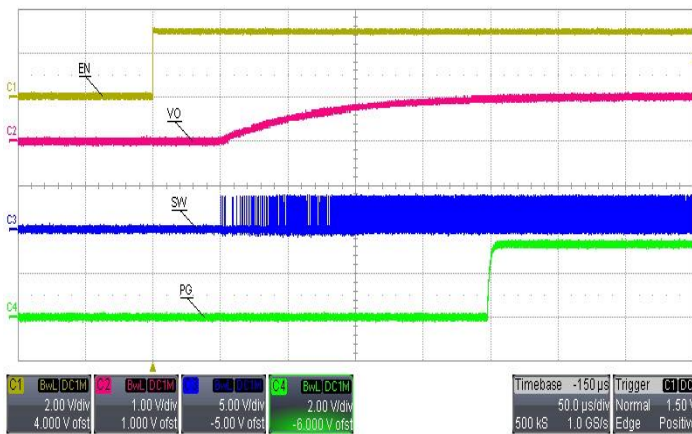
**Power ON from VCC**  
CH1:VCC, CH2:VO, CH3:SW,CH4:PG



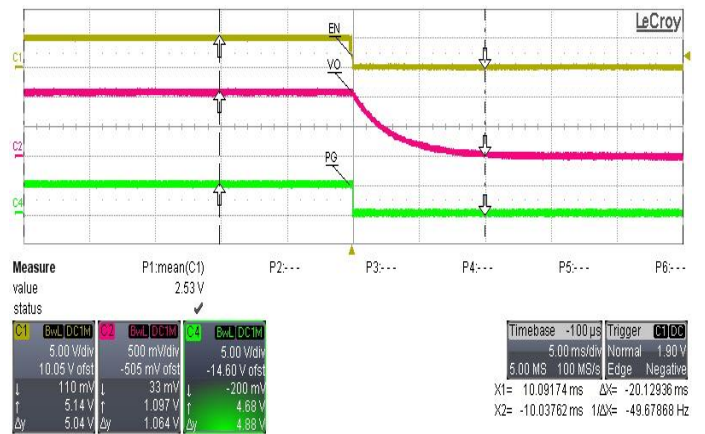
**Power ON from VIN**  
CH1:VCC, CH2:VO, CH3:SW,CH4:PG



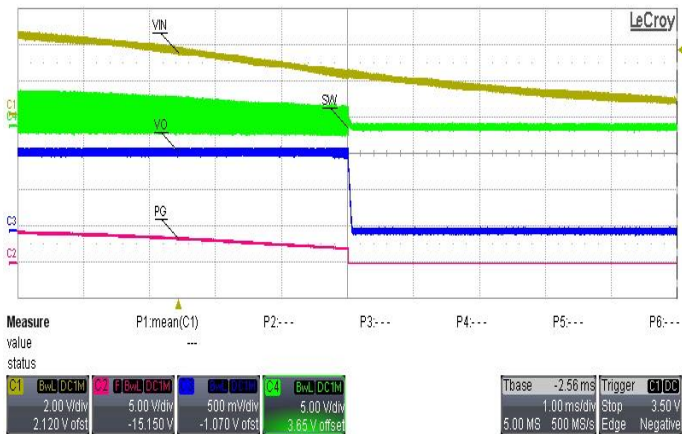
**Power On from Enable**  
CH1:VCC, CH2:VO, CH3:SW,CH4:PG



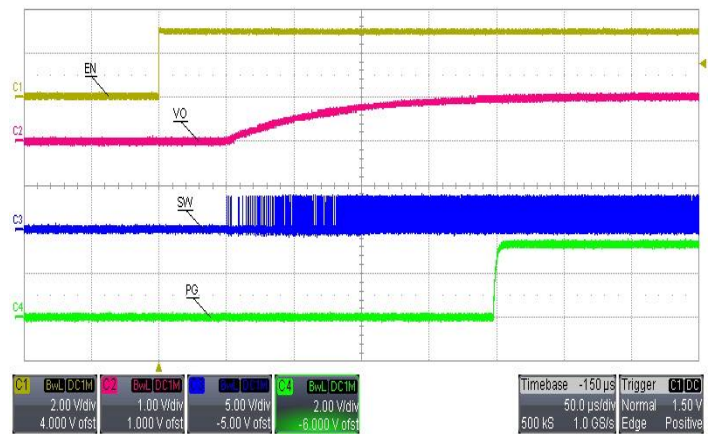
**No Load Soft-Stop**  
CH1:EN, CH2:VO, CH3:PG



**Power Off from VIN**  
CH1:VIN, CH2:PG, CH3:VO,CH4:VIN

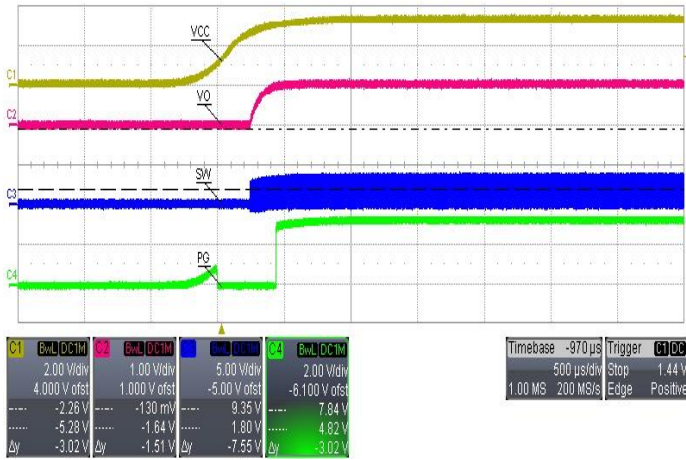


**Power Good Signal when Power On**  
CH1:VCC, CH2:VO, CH3:SW,CH4:PG

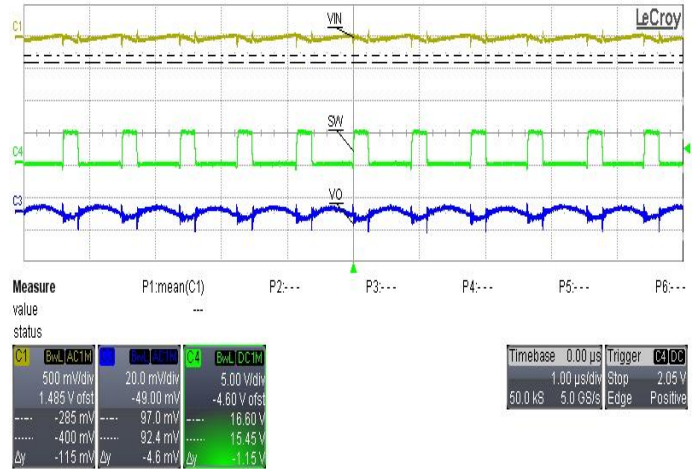




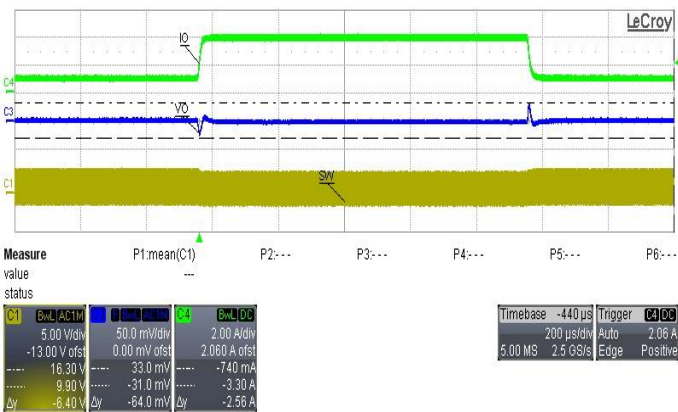
**VIN=VCC 3.3V Power On**  
**CH1:VCC, CH2:VO, CH3:SW,CH4:PG**



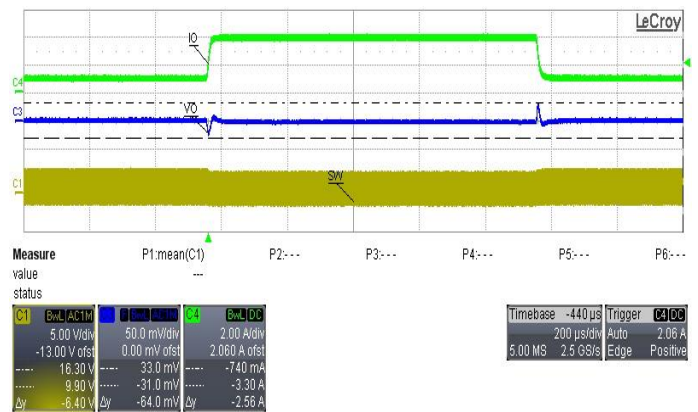
**Output Voltage Ripple**  
**CH1:VIN(ac), CH2:Vo(ac), CH3:SW**



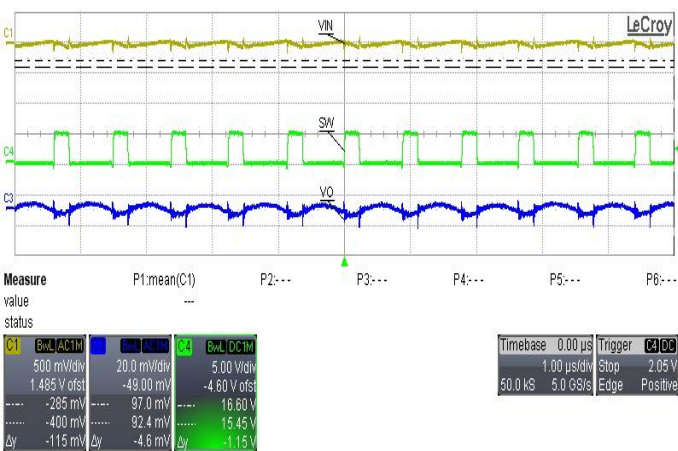
**1A to 4A Transient Response**  
**CH1:SW, CH2:Vo(ac), CH4:Io**



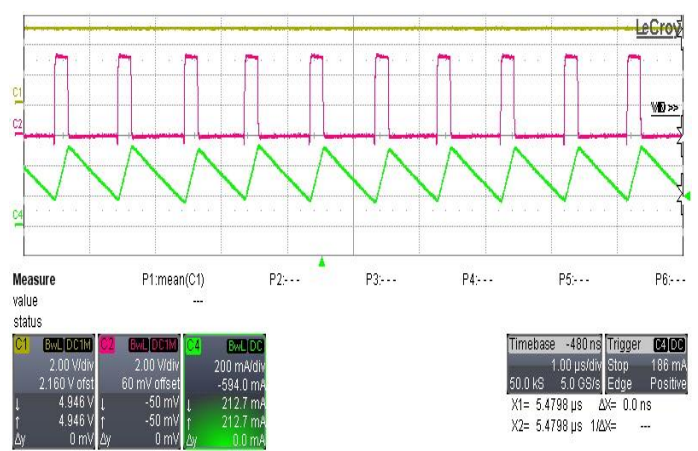
**Light Load to Heavy Load Transition**  
**CH1:SW, CH2:Vo(ac), CH4:Io**



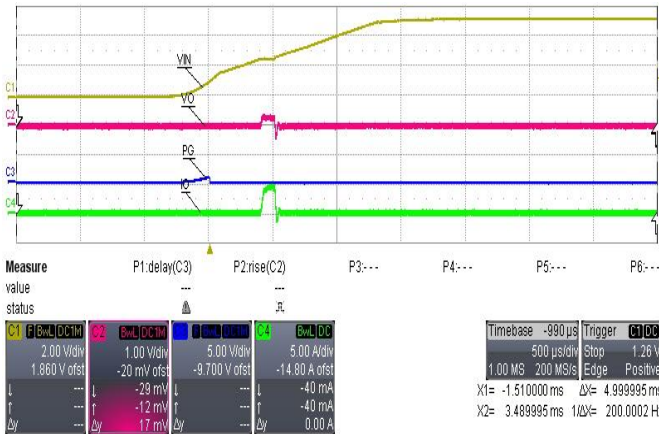
**No Load Operation**  
**CH1:VIN(ac), CH3:Vo(ac), CH4:SW**



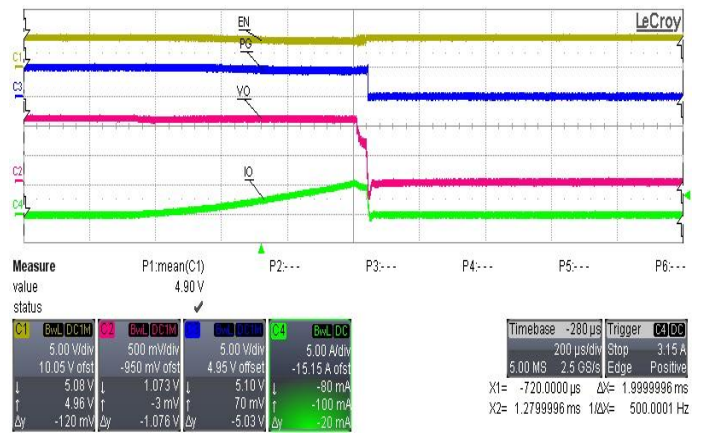
**Normal Load Operation**  
**CH1:VIN, CH2:SW, CH4:IL**



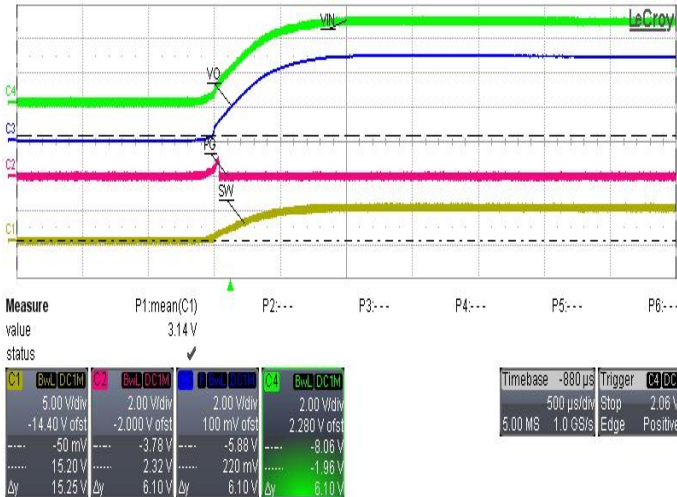
**Vo Pre-Short Protection**  
**CH1:VIN, CH2:VO, CH3:PG, CH4:IO**



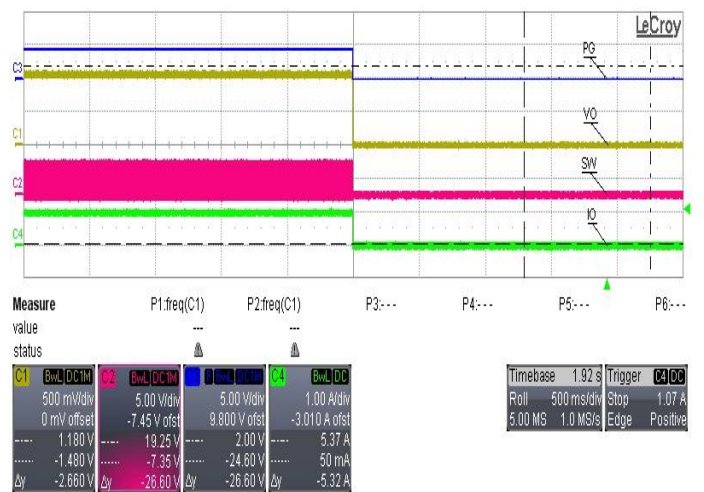
**Vo Over Load Protection**  
**CH1:EN, CH2:Vo, CH3:PG, CH4:Io**



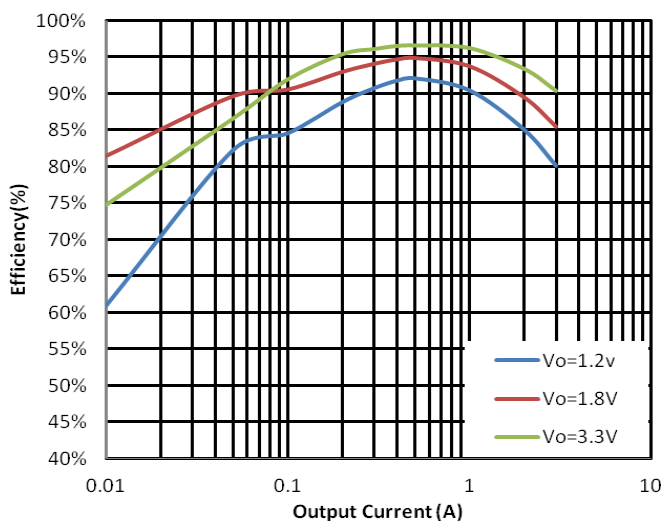
**Vo Over Voltage Protection**  
**CH1:SW, CH2:PG, CH3:Vo, CH4:VIN**



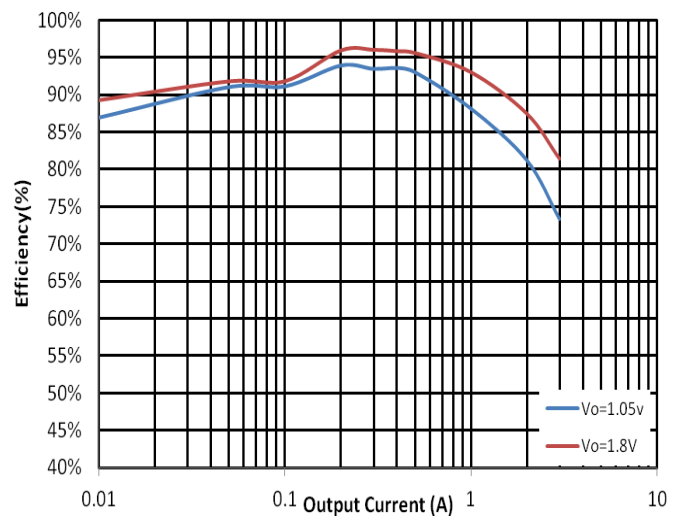
**Over Temperature Protection**  
**CH1:Vo, CH2:SW, CH3:PG, CH4:Io**

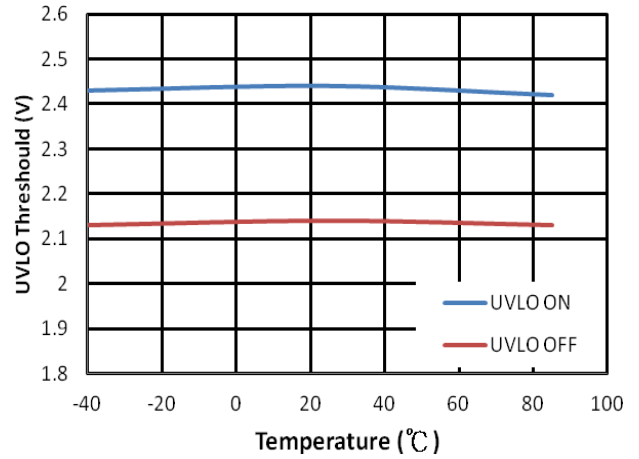
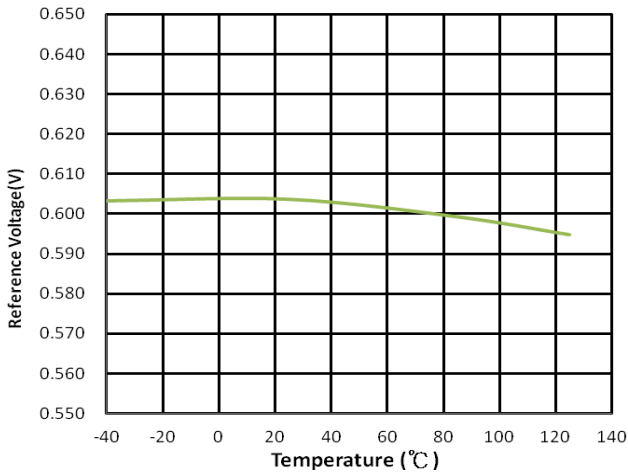


**VIN 5V Efficiency**

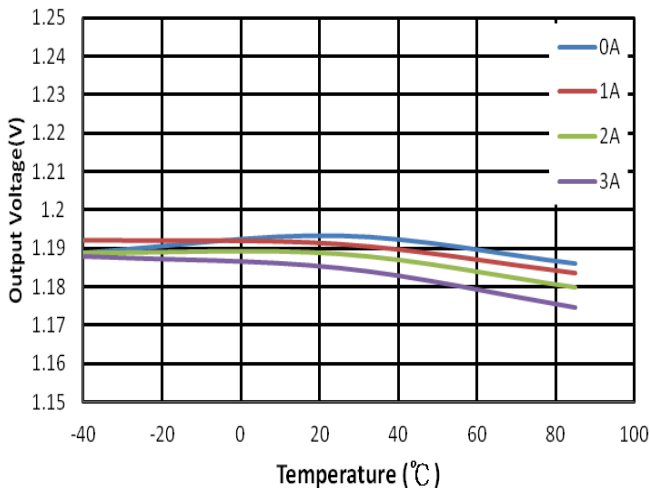


**VIN 3.3V Efficiency**

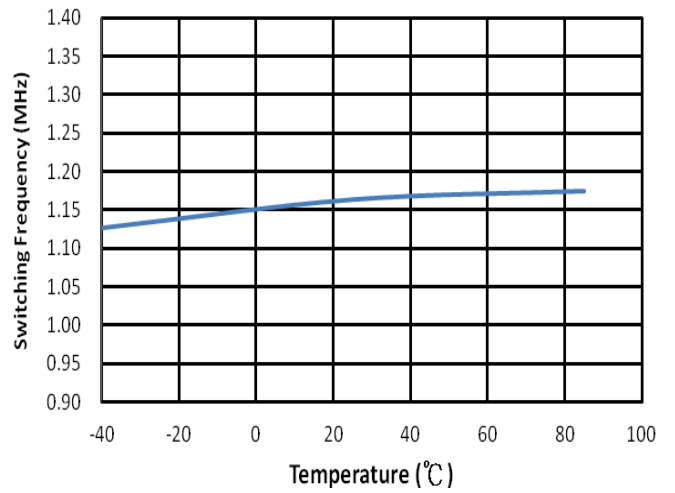




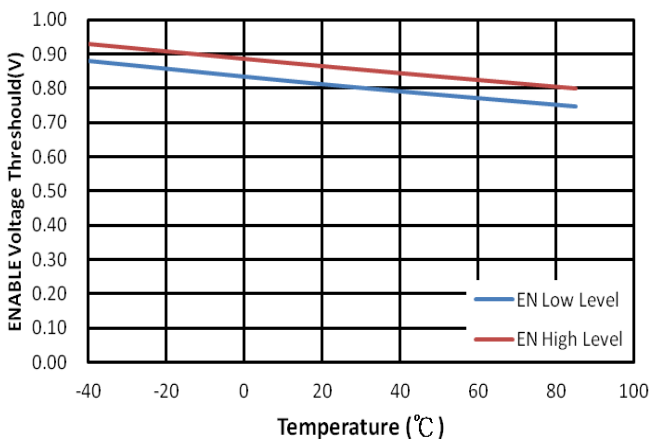
Output Voltage with Load VS. Temperature



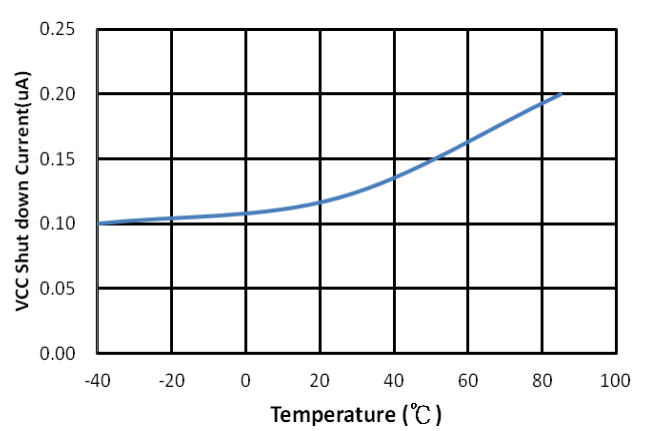
Switching Frequency VS. Temperature



Enable Threshold VS. Temperature



VCC Shutdown Current VS. Temperature





## Functional Description

### Theory of Operation

The EM5841D is a step-down dc-dc regulator that uses pseudo-fixed frequency constant-on-time control architecture with integrated high-side switch and low-side synchronous rectifier. The high switch frequency and tiny 3X3-10 pin DFN package enables the user to optimize the solution for minimum board space and efficiency.

The buck regulator employs pseudo-fixed frequency constant-on time control. This control method allows fast transient response than traditional current-mode control scheme thereby reducing the total component count due to lowering the size of the output capacitance.

### Constant On-Time Control

The PWM control scheme used by constant on-time control, the high side switch on-time is determined by internal pulse generator. The pulse period is determined by  $V_o$  and  $V_{IN}$  information from  $V_{IN}$  and SW pin; the period is proportional to output voltage and inversely proportional to input voltage. The advantages of this control scheme are such as fast transient response, without external compensation and less output component count than other control method.

### Soft-Start and Soft-Stop Function

The EM5841D has built-in soft-start function that ramps up the output voltage at constant slew rate to avoid output overshooting at start-up. The internal soft-start time from EN to PG active is typically about 400us (Max).

The output soft-stop operation is active when the EN from high to low. An internal discharge resistor typically 100  $\Omega$  is enabled in this condition to discharge the output capacitor through SW pin.

### Chip Enable

When the input voltage exceeds the under voltage lockout (UVLO) threshold 2.4V typically, the EM5841D will be enabled by pulling the EN pin high. Leaving the EN pin floating or grounded will disable the chip. There is an internal 1M $\Omega$  resistor from the EN pin to ground.

### Input UVLO Protection on VCC and VIN

The EM5841D have input under voltage lockout protection (UVLO), if the input voltage exceeds the UVLO on threshold 2.4V typically, and there is typically a 100us delay for internal circuit waking up then soft-start begins. The device will shut off if  $V_{cc}$  or  $V_{IN}$  falls below UVLO level.

### Current limit Protection

The EM5841D have a minimum 5A current limit level for high side switch. If the internal high side sensing current is above this level, the FET will stop switching immediately and low-side FET will be turned on until the current level drops below the hysteresis window of current limit level.

### Output Under-Voltage Protection

Output under-voltage protection works in conjunction with the current limit protection. If the FB voltage drops below 50% internal  $V_{REF}$ , after a delay of 7.5us, the converter will be latched off. Under-voltage protection can be released by toggling the EN/ $V_{IN}$  or VCC.

### Output Over-Voltage Protection

If the FB voltage above 140% internal VREF, after a delay of 7.5us, the converter will be latched off. Over-voltage protection can be released by toggling the EN/VIN or VCC.

## Functional Description

### Power Good Indicator

The power good output is an open-drain output which requires a pull-up resistor. When the output voltage is 10% below the nominal voltage, PG is pulled low. It is held low until the output voltage returns to the nominal voltage. PG is held low during soft-start and activated about 1ms after output voltage reaches its regulation.

### Over Temperature Protection

Over thermal protection limits the total power dissipation in the device, when the junction temperature exceeds 150°C, an internal thermal sensor shut down the device and allowing the IC to cooling down. The device will turn on again after the junction temperature cools by 25°C.

### Switching Frequency Variation

The switching frequency varies with load current as a results of the power losses in the MOSFETs and the inductor. For a traditional PWM constant frequency converter, as the load increases the duty cycle also increases slightly to compensate for total losses in the integrated MOSFETs and DCR losses in the inductor. A constant on time control converter must also compensate this kind of losses. The on time is essentially fixed for a given Vo and VIN combination, to compensate the losses the off-time will tend to reduce slightly by constant on time loop controlled as load increases. For this reason, the switching frequency increases slightly with increasing load.

## Application Information

### Input Capacitor Selection

The first objective in selecting input capacitors is to reduce the ripple voltage amplitude seen at the input of the converter. Ceramic capacitors placed right at the input of the regulator reduce ripple voltage. These capacitors must be placed close to

the converter input pins to be effective. High quality ceramic input capacitor, such as X5R or X7R and greater than 10uF are recommended for the input capacitor due to more stable temperature characteristic.

The input ripple voltage of converter is decided by the value of input capacitance. Input ripple voltage  $\Delta V_{IN}$  can be calculated by the following equation.

$$\Delta V_{IN} = \frac{I_{O(Max)} \times V_O}{C_{IN} \times F_{SW} \times V_{IN}}$$

The RMS current rating of the input capacitor should be larger than the following equation.

$$\Delta I_{RMS} = I_O \times \sqrt{D \times (1 - D)}$$

### Inductor Selection

For a given input and output voltage, the inductor value and switching frequency determine the inductor ripple current. The ripple current increases with higher VIN and decreases with high inductance, the lower the ripple current reduces the core losses in the inductor, and output ripple voltage. A good starting point for selecting the ripple current is  $\Delta I_L \leq 0.3 \cdot I_{O(MAX)}$ , so the inductor value should be chosen according to the following equation:

$$L = \left( \frac{V_O}{F_{SW} \times \Delta I_{L(MAX)}} \right) \cdot \left( 1 - \frac{V_O}{V_{IN}} \right)$$

When selecting an inductor, make sure that it is capable of supporting the peak output current without saturating. Inductor saturation will result in a sudden reduction in inductance that may cause the unstable operation.

### Output Voltage Setting Resistor Selection

The device with an external adjustable output voltage, the output voltage is programmed by an external resistor divider connected from  $V_o$  to  $V_{FB}$  and then to AGND, as shown in the typical application schematic. The programmed output voltage is below,

$$V_o = V_{FB} \cdot \left(1 + \frac{R_1}{R_2}\right)$$

Where  $V_{FB}$  is equal to the internal reference voltage 0.6V,  $R_1$  is the resistance from  $V_o$  to FB,  $R_2$  is from VFB to AGND, and increases the quiescent current by  $R_1$  and  $R_2$ , so larger resistance is desirable, select the  $R_2$  no larger than  $200k\Omega$  is preferable.

### Output Capacitor Selection

An output capacitor is required to filter the inductor current. Output ripple and transient response are two critical factors when choosing the output capacitance. The COT mode allows for the usage of low ESR ceramic capacitors and thus smaller board layout, electrolytic capacitors may also be used. The following equations allow calculation of the required capacitance to meet a desired output ripple voltage.

For the ceramic capacitors (low ESR):

$$V_{OUTRIPPLE} = \frac{\Delta I_L}{8 * F_{SW} * C_o}$$

When using electrolytic capacitors (High ESR):

$$V_{OUTRIPPLE} = \Delta I_L * ESR$$

Regarding transient response considerable, a good starting point is to determine the allowable overshoot in  $V_o$  if the load is suddenly released. In this case, energy stored in the inductor will be transferred to  $C_o$  causing its voltage to rising, so choosing the needs capacitance should be cover for both ripple and transient requirement. The most of applications will require a minimum of 22uF output capacitance. Like the input capacitor multilayer ceramic capacitors are X7R or X5R types. The maximum RMS current rating of the capacitors is:

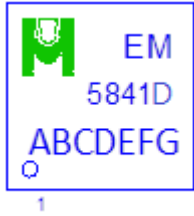
$$I_{CORMS} = \frac{1}{\sqrt{12}} \times \frac{V_o (V_{IN(MAX)} - V_o)}{L \times F_{SW} \times V_{IN(MAX)}} A_{RMS}$$

### Layout Considerations

- The VIN, VCC decoupling capacitors should be as closed to the IC VIN and VCC pin.
- The FB voltage divider network should be as closed to the IC FB pin and away from switching node.
- Use widely trance for the High current path, From VIN, SW,  $V_o$  to GND path.
- Widely ground plan for good heat sinking and better noise immunity.

**Ordering & Marking Information**

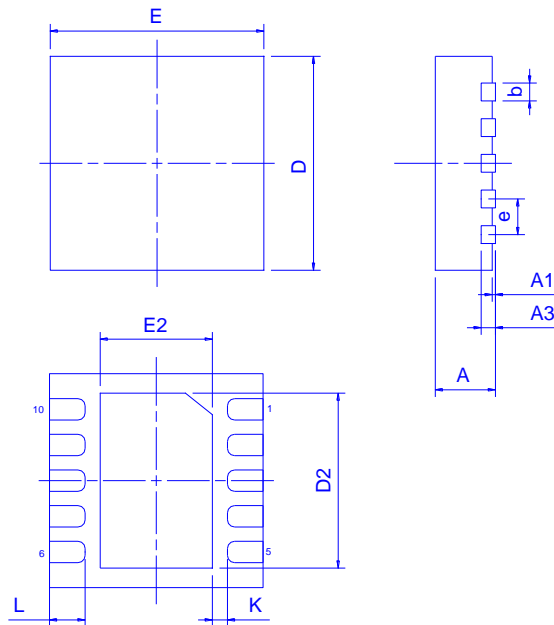
Device Name: EM5841DVT for DFN3.0X3.0-10



→ EM5841D Device Name

→ ABCDEFG: Date Code

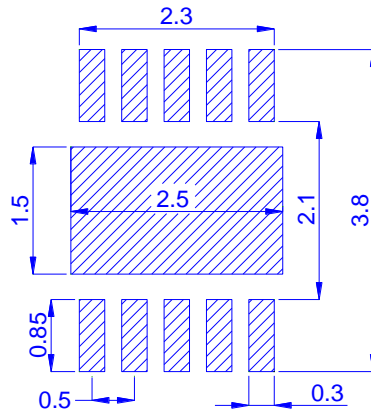
**Outline Drawing**



Dimension in mm

Dimension	A	A1	A3	b	D	E	D2	E2	e	L	K
Min.	0.7	0.00		0.18			2.20	1.40		0.30	0.20
Typ.	0.75	0.02	0.2	0.25	3.0	3.0			0.50	0.40	
Max.	0.80	0.05		0.30			2.70	1.75		0.50	

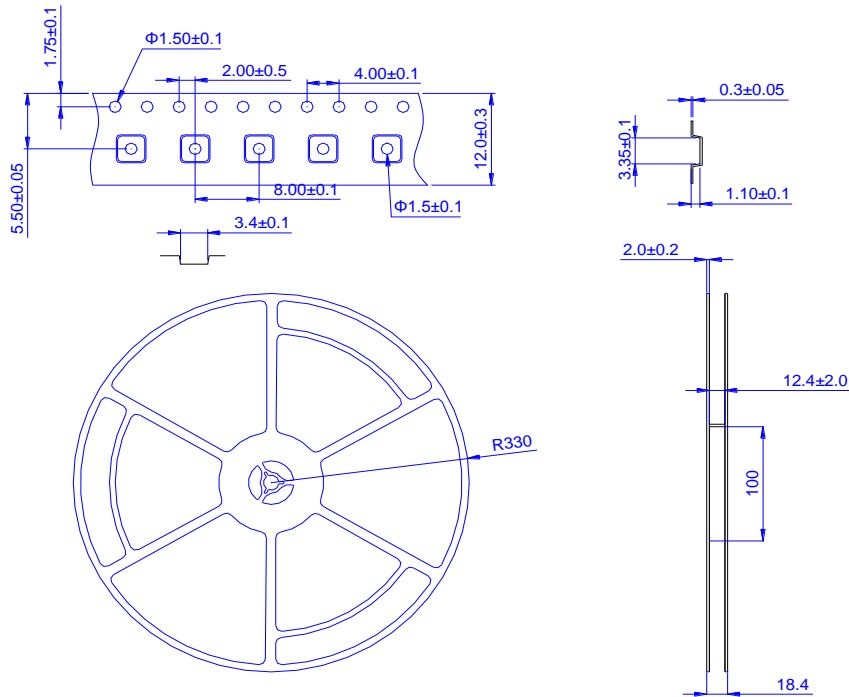
Recommended minimum pads







◆ Tape & Reel Information : 5000pcs/Reel



Package	DFN3.0X3.0-10
Reel Dimensions	13"
Pin1 Orientation	<p>FEED DIRECTION</p>
Leader Empty Pockets	50
Trailer Empty Pockets	50
Quantity per Reel	5K
Reel / Inner Box	1 : 1
Quantity per Inner Box	5K
Inner Box/ Outer Carton	10 : 1
Quantity per Outer Carton	50K



Rev.	Change List	Date.
A.0	Initial release	2019/5/15